74F821 10-Bit D-Type Flip-Flop

FAIRCHILD

SEMICONDUCTOR

74F821 10-Bit D-Type Flip-Flop

General Description

Features

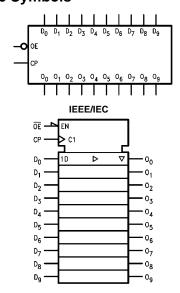
■ 3-STATE Outputs

The 74F821 is a 10-bit D-type flip-flop with 3-STATE true outputs arranged in a broadside pinout.

Ordering Code:

Order Number	Package Number	Package Description					
74F821SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide					
74F821SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide					
Devices also available	Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.						

Logic Symbols



Connection Diagram

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ŌĒ —	1	—	24	-v _{cc}
D ₀ —	2		23	-0 ₀
D1-	3		22	-0 ₁
D ₂ —	4		21	-0 ₂
D3 —	5		20	-0 ₃
D4 -	6		19	-0 ₄
D ₅ —	7		18	-0 ₅
D ₆ -	8		17	-0 ₆
D ₇ —	9		16	-0 ₇
D ₈ -	10		15	-0 ₈
D ₉ —	11		14	-0 ₉
GND —	12		13	- CP

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74F821

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}		
D ₀ -D ₉	Data Inputs	1.0/1.0	20 μA/-0.6 mA		
OE	Output Enable	1.0/1.0	20 µA/-0.6 mA		
	3-STATE Input				
CP	Clock Input	1.0/1.0	20 µA/–0.6 mA		
O ₀ –O ₉	3-STATE Outputs	150/40 (33.3)	-3.0 mA/24 mA (20 mA		

Functional Description

The 74F821 consists of ten D-type edge-triggered flipflops. This device has 3-STATE true outputs for bus systems organized in a broadside pinning. The buffered Clock (CP) and buffered Output Enable (\overline{OE}) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH CP transition. With the OE LOW the content of the flip-flops are available at the outputs. When the $\overline{\text{OE}}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{\text{OE}}$ input does not affect the state of the flip-flops.

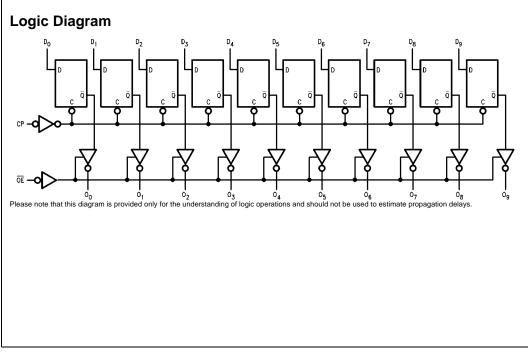
Function Table

I	Inputs		Internal Output		Function
OE	СР	D	Q	0	Function
Н	Н	Х	NC	Z	Hold
н	L	Х	NC	Z	Hold
н	~	L	Н	Z	Load
Н	~	Н	L	Z	Load
L	~	L	Н	L	Data Available
L	~	Н	L	Н	Data Available
L	Н	Х	NC	NC	No Change in Data
L	L	Х	NC	NC	No Change in Data

L = LOW Voltage Level H = HIGH Voltage Level

X = Immaterial

NC = No Change



Absolute Maximum Ratings(Note 1)

Storage Temperature Ambient Temperature under Bias Junction Temperature under Bias V_{CC} Pin Potential to Ground Pin Input Voltage (Note 2) Input Current (Note 2) Voltage Applied to Output in HIGH State (with $V_{CC} = 0V$) Standard Output 3-STATE Output Current Applied to Output in LOW State (Max) twice the rated I_{OL} (mA)

-65°C to +150°C $-55^{\circ}C$ to $+125^{\circ}C$ $-55^{\circ}C$ to $+150^{\circ}C$ -0.5V to +7.0V -0.5V to +7.0V -30 mA to +5.0 mA

-0.5V to V_{CC}

-0.5V to +5.5V

Recommended Operating Conditions

Free Air Ambient Temperature Supply Voltage

 $0^{\circ}C$ to $+70^{\circ}C$

+4.5V to +5.5V

74F821

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Symbol	Parameter	Min	Тур	Max	Units	V _{cc}	Conditions	
VIH	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signa
VIL	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA	
V _{OH}	Output HIGH Voltage	10% V _{CC} 10% V _{CC} 5% V _{CC}	2.5 2.4 2.7 2.7			v	Min	$I_{OH} = -1 \text{ mA}$ $I_{OH} = -3 \text{ mA}$ $I_{OH} = -1 \text{ mA}$
V _{OL}	Output LOW Voltage	5% V _{CC} 10% V _{CC}	2.1		0.5	v	Min	$I_{OH} = -3 \text{ mA}$ $I_{OL} = 24 \text{ mA}$
Ι _{ΙΗ}	Input HIGH Current				5.0	μΑ	Max	V _{IN} = 2.7V
I _{BVI}	Input HIGH Current Breakdown Test				7.0	μΑ	Max	V _{IN} = 7.0V
ICEX	Output HIGH Leakage Current				50	μΑ	Max	V _{OUT} = V _{CC}
V _{ID}	Input Leakage Test		4.75			v	0.0	I _{ID} = 1.9 μA, All Other Pins Grounded
I _{OD}	Output Leakage Circuit Current				3.75	μΑ	0.0	V _{IOD} = 150 mV All Other Pins Grounded
IIL	Input LOW Current				-0.6	mA	Max	$V_{IN} = 0.5V$
I _{OZH}	Output Leakage Current				50	μΑ	Max	V _{OUT} = 2.7V
I _{OZL}	Output Leakage Current				-50	μΑ	Max	$V_{OUT} = 0.5V$
I _{OS}	Output Short-Circuit Current		-60		-150	mA	Max	V _{OUT} = 0V
I _{CCZ}	Power Supply Current			78	100	mA	Max	V _O = HIGH Z

DC Electrical Characteristics

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3

Symbol	Parameter	T _A = +25°C V _{CC} = +5.0V C _L = 50 pF			$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = +5.0V$ $C_L = 50 \text{ pF}$		$T_A = 0^\circ C \text{ to } +70^\circ C$ $V_{CC} = +5.0V$ $C_L = 50 \text{ pF}$		Units
		Min	Тур	Max	Min	Max	Min	Max	
f _{MAX}	Maximum Clock Frequency	100	150		60		70		MHz
t _{PLH}	Propagation Delay	2.0	6.4	9.5	2.0	10.5	2.0	10.5	
t _{PHL}	CP to O _n	2.0	6.2	9.5	2.0	10.5	2.0	10.5	ns
t _{PZH}	Output Enable Time	2.0	5.8	10.5	2.0	13.0	2.0	11.5	
t _{PZL}	OE to On	2.0	6.3	10.5	2.0	13.0	2.0	11.5	
t _{PHZ}	Output Disable Time	1.5	3.4	7.0	1.0	7.5	1.5	7.5	ns
t _{PLZ}	OE to On	1.5	3.5	7.0	1.0	7.5	1.5	7.5	

AC Operating Requirements

Symbol	Parameter	~	$T_A = +25^{\circ}C$ $V_{CC} = +5.0V$		$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = +5.0V$		$T_A = 0^{\circ}C \text{ to } +70^{\circ}C$ $V_{CC} = +5.0V$	
		Min	Max	Min	Max	Min	Max	
t _S (H)	Setup Time, HIGH or LOW	2.5		4.0		3.0		
t _S (L)	D _n to CP	2.5		4.0		3.0		
t _H (H)	Hold Time, HIGH or LOW	2.5		2.5		2.5		ns
t _H (L)	D _n to CP	2.5		2.5		2.5		
t _W (H)	CP Pulse Width	5.0		6.0		6.0		
t _W (L)	HIGH or LOW	5.0		6.0		6.0		ns

